TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC02AP, TC74HC02AF, TC74HC02AFN

QUAD 2-INPUT NOR GATE

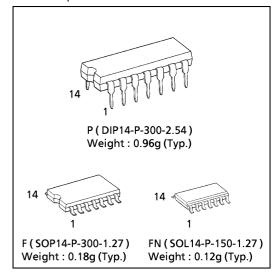
The TC74HC02A is a high speed CMOS 2-INPUT NOR GATE fabricated with silicon gate C2MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including a buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

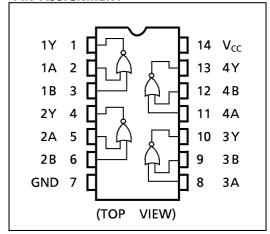
FEATURES:

- High Speed······ t_{pd} = 6ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ············· $I_{CC} = 1 \mu A(Max.)$ at Ta = 25°C
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Output Drive Capability 10 LSTTL Loads
- Symmetrical Output Impedance··· | I_{OH} | = I_{OL} = 4mA(Min.)
- Balanced Propagation Delays $\cdots t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr.) = 2V~6V
- Pin and Function Compatible with 74LS02

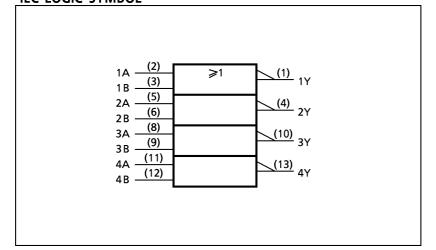
(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE

Α	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{cc}	− 0.5~7	V
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	٧
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} / Ground Current	I _{cc}	± 50	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

*500mW in the range of Ta= $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$. From Ta=65°C to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2~6	<
Input Voltage	V _{IN}	0~V _{cc}	>
Output Voltage	V _{OUT}	0~V _{cc}	٧
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	t _r , t _f	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

DC ELECTRICAL CHARACTERISTICS

DADAMETED	CVARDO	TEST CONDITION		V _{cc}	1	Ta = 25°C			Ta = −40~85°C	
PARAMETER	SYMBOL	1531 CC	TEST CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	VIH				1.50 3.15 4.20	_ _ _	_ _ _	1.50 3.15 4.20		V
Low - Level Input Voltage	VIL			2.0 4.5 6.0	_ _ _	_ _ _	0.50 1.35 1.80		0.50 1.35 1.80	v
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	_ _ _	1.9 4.4 5.9	_ _ _	V
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	<u>-</u>	4.13 5.63	_	
Low - Level Output Voltage	V _{OL}	V _{OI} V _{IN} =	I _{OL} = 20μΑ	2.0 4.5 6.0	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	v
	V _{IH} or V _{IL}	$I_{OL} = 4 mA$ $I_{OL} = 5.2 mA$	4.5 6.0	_	0.17 0.18	0.26 0.26	_	0.33 0.33		
Input Leakage Current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	_		± 0.1	_	± 1.0	_
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC}$ or GND		6.0	_	_	1.0	_	10.0	μ A

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AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t _{TLH} t _{THL}		_	4	8	ns
Propagation Delay Time	t _{pLH} t _{pHL}		1	6	12	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		Ta = -4	UNIT		
FARAIVIETER			$V_{CC}(V)$	MIN.	TYP.	MAX.	MIN.	MAX.	
	t _{TLH}		2.0	_	25	75	_	95	
Output Transition Time			4.5	_	7	15	_	19	
	t _{THL}		6.0	_	6	13	_	16	ns
	+		2.0	-	27	75	_	95	
Propagation Delay Time	t _{pLH}		4.5	_	9	15	_	19	
	t _{pHL}		6.0	-	8	13	_	16	
Input Capacitance	C _{IN}				5	10	_	10	20
Power Dissipation Capacitance	C _{PD} (1)			_	21	_	_	_	pF

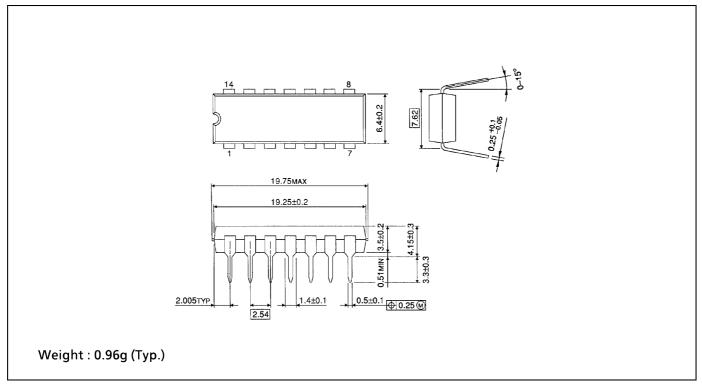
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4$ (per Gate)

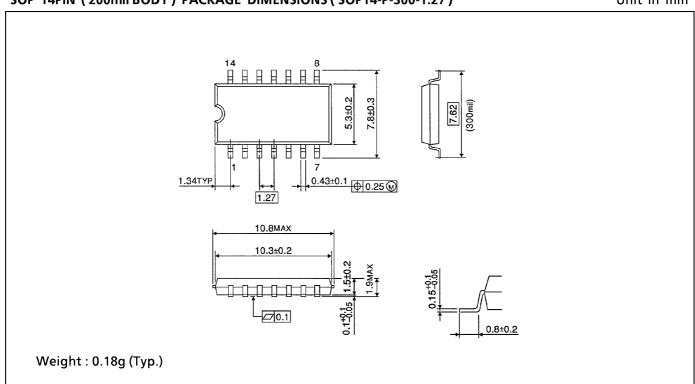
DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

Unit in mm



SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

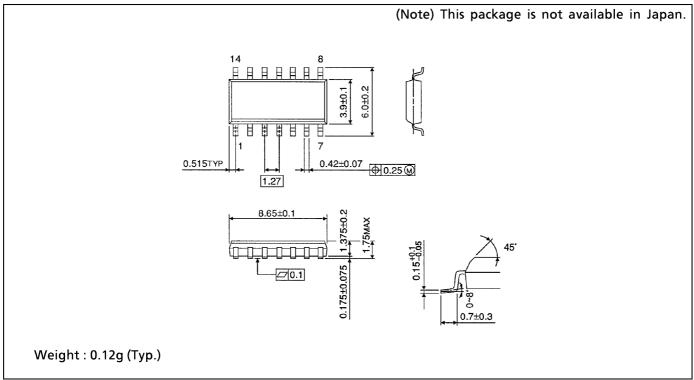
Unit in mm



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SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



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